

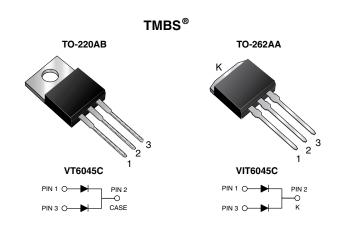
FREE



Vishay General Semiconductor

Dual Low-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.33 \text{ V}$ at $I_F = 10 \text{ A}$



| PRIMARY CHARACTERISTICS | | | | | |
|---|----------|--|--|--|--|
| I _{F(AV)} | 2 x 30 A | | | | |
| V _{RRM} | 45 V | | | | |
| I _{FSM} | 320 A | | | | |
| V _F at I _F = 30 A | 0.47 V | | | | |
| T _J max. | 150 °C | | | | |

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses

High efficiency operation
COMPLIANT
HALOGEN

• Solder dip 275 °C max. 10 s, per JESD 22-B106

• AEC-Q101 qualified

- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS compliant, and AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable pe J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | | | |
|--|------------|-----------------------------------|---------|----------|------|--|
| PARAMETER | | SYMBOL | VT6045C | VIT6045C | UNIT | |
| Maximum repetitive peak reverse voltage | | V_{RRM} | 45 | | V | |
| Maximum average forward rectified current (fig. 1) | per device | 1 | 60 | | А | |
| | per diode | I _{F(AV)} | 30 | | | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode | | I _{FSM} | 320 | | А | |
| Operating junction and storage temperature range | | T _J , T _{STG} | - 40 to | + 150 | °C | |

VT6045C, VIT6045C

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| ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | | |
|---|--|-------------------------|-------------------------------|------|------|------|--|
| PARAMETER | TEST CONDITIONS | | SYMBOL | TYP. | MAX. | UNIT | |
| Instantaneous forward voltage per diode | I _F = 10 A | T _A = 25 °C | V _F ⁽¹⁾ | 0.44 | - | V | |
| | I _F = 15 A | | | 0.47 | - | | |
| | I _F = 30 A | | | 0.54 | 0.64 | | |
| | I _F = 10 A | T _A = 125 °C | | 0.33 | - | | |
| | I _F = 15 A | | | 0.37 | - | | |
| | I _F = 30 A | | | 0.47 | 0.56 | | |
| Reverse current per diode | V _R = 45 V | T _A = 25 °C | I _R ⁽²⁾ | - | 3000 | μΑ | |
| | V _R = 45 V T _A = 125 °C | T _A = 125 °C | | 18 | 50 | mA | |

Notes

⁽²⁾ Pulse test: Pulse width ≤ 40 ms

| THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | |
|---|------------|----------------|---------|----------|------|--|
| PARAMETER | | SYMBOL | VT6045C | VIT6045C | UNIT | |
| Typical thermal resistance | per diode | В | 1.5 | | °C/W | |
| | per device | $R_{	heta JC}$ | 0.8 | | | |

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|--------------------|-----------------|--------------|---------------|---------------|--|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | | |
| TO-220AB | VT6045C-M3/4W | 1.89 | 4W | 50/tube | Tube | | |
| TO-262AA | VIT6045C-M3/4W | 1.46 | 4W | 50/tube | Tube | | |
| TO-220AB | VT6045CHM3/4W (1) | 1.89 | 4W | 50/tube | Tube | | |
| TO-262AA | VIT6045CHM3/4W (1) | 1.46 | 4W | 50/tube | Tube | | |

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

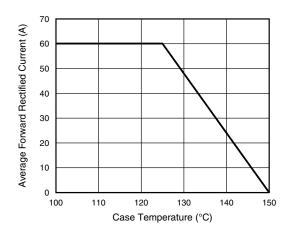


Fig. 1 - Maximum Forward Current Derating Curve

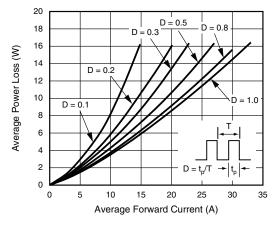


Fig. 2 - Forward Power Loss Characteristics Per Diode

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽¹⁾ AEC-Q101 qualified



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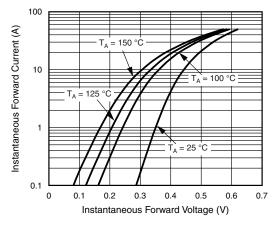


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

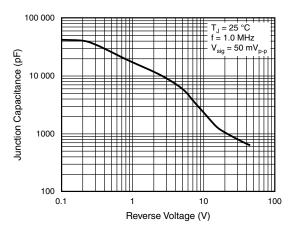


Fig. 5 - Typical Junction Capacitance Per Diode

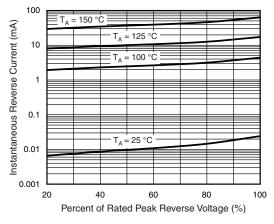


Fig. 4 - Typical Reverse Characteristics Per Diode

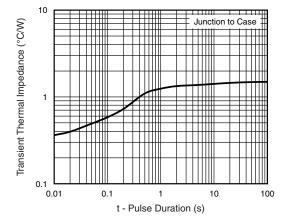


Fig. 6 - Typical Transient Thermal Impedance Per Diode

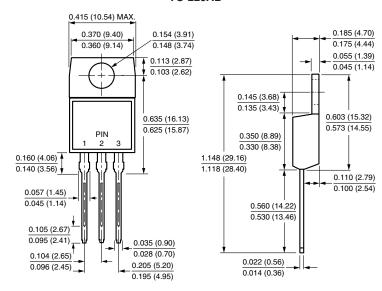
VT6045C, VIT6045C

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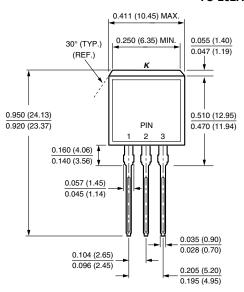


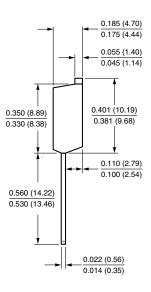
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB



TO-262AA









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